NSN 5961-01-533-3180

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-533-3180 **Inclosure Material:** Metal and glass **End Application:** An/frt-31, transmitting set, radio **Mounting Facility Quantity: Mounting Method:** Threaded stud **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 1200.0 repetitive peak off-state voltage **Current Rating Per Characteristic:** 230.00 amperes forward current, total rms universal **Power Rating Per Characteristic:** 10.0 watts small-signal input power, common-collector blank **Product Name:** Phase control thyristors **Terminal Type And Quantity:** 3 insulated wire lead w/terminal lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig:

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